

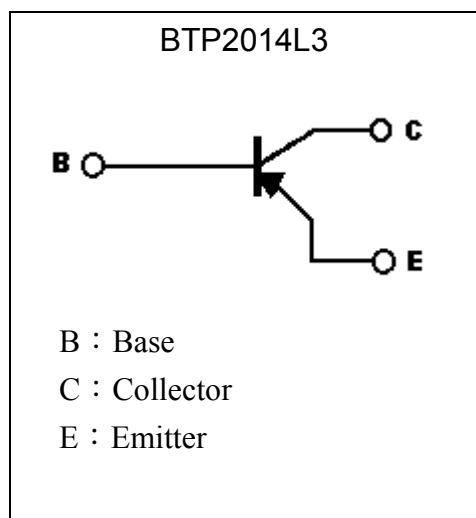
**PNP Epitaxial Planar High Current (High Performance) Transistor**

# BTP2014L3

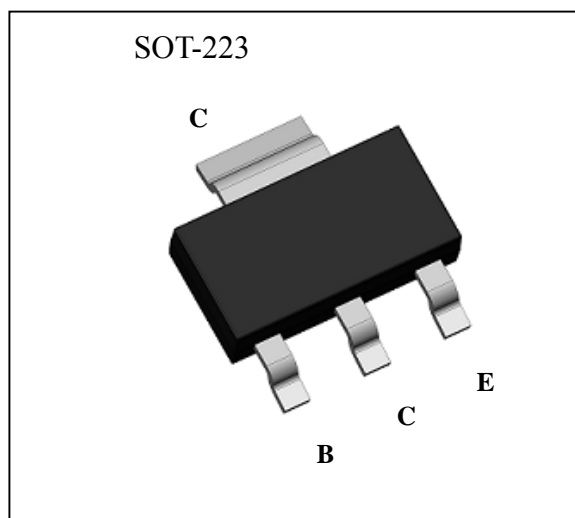
## Features

- 4 Amps continuous current, up to 10 Amps peak current
- Very low saturation voltage
- Extremely low equivalent on resistance,  $R_{CE(SAT)}=79m\Omega$  typ. at 3A
- Pb-free lead plating and halogen-free package

## Symbol

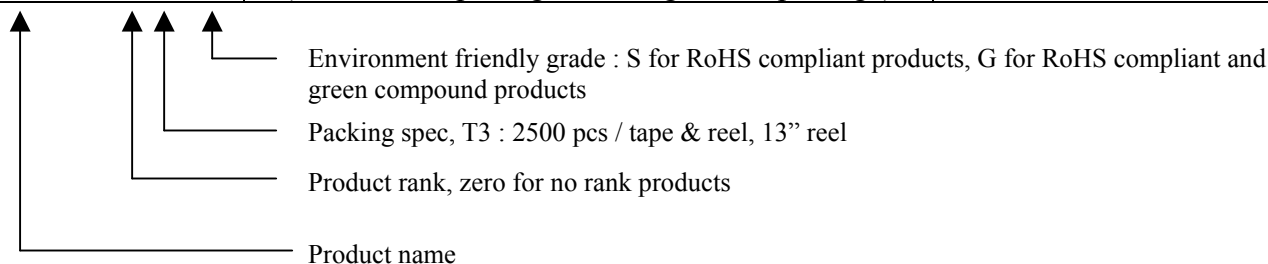


## Outline



## Ordering Information

Device	Package	Shipping
BTP2014L3-0-T3-G	SOT-223 (Pb-free lead plating and halogen-free package)	2500 pcs / Tape & Reel





**Absolute Maximum Ratings** (Ta=25°C)

Parameter	Symbol	Limits	Unit
Collector-Base Voltage	V <sub>CB0</sub>	-180	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-140	V
Emitter-Base Voltage	V <sub>EBO</sub>	-7	V
Continuous Collector Current	I <sub>C</sub>	-4	A
Peak Collector Current	I <sub>CP</sub>	-10	A
Base Current	I <sub>B</sub>	-1	A
Power Dissipation @T <sub>A</sub> =25°C	P <sub>D</sub>	3 (Note 1)	W
		1.6 (Note 2)	W
Operating and Storage Temperature Range	T <sub>j</sub> ; T <sub>stg</sub>	-55 ~ +150	°C

**Thermal Data**

Parameter	Symbol	Value	Unit
Thermal Resistance, Junction-to-case, max	R <sub>θJC</sub>	12.5	°C/W
Thermal Resistance, Junction-to-ambient, max	R <sub>θJA</sub>	41.7 (Note 1)	°C/W
Thermal Resistance, Junction-to-ambient, max		78 (Note 2)	°C/W

Note: 1.For a device surface mounted on 52mm×52mm×1.6mm FR 4 PCB of 2oz. copper, in still air condition.  
 2.For a device surface mounted on 25mm×25mm×1.6mm FR 4 PCB of 1oz. copper, in still air condition.

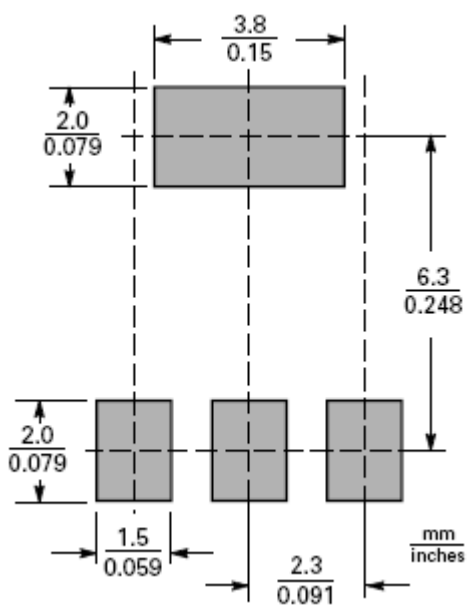
**Characteristics** (Ta=25°C, unless otherwise specified)

Symbol	Min.	Typ.	Max.	Unit	Test Conditions
BV <sub>CB0</sub>	-180	-200	-	V	I <sub>C</sub> =-100μA
BV <sub>CER</sub>	-180	-200	-	V	I <sub>C</sub> =-1μA, R <sub>BE</sub> ≤1kΩ
*BV <sub>CEO</sub>	-140	-160	-	V	I <sub>C</sub> =-10mA
BV <sub>EBO</sub>	-7	-8	-	V	I <sub>E</sub> =-100μA
I <sub>CB0</sub>	-	-	-20	nA	V <sub>CB</sub> =-150V
I <sub>CER</sub>	-	-	-20	nA	V <sub>CE</sub> =-150V, R <sub>BE</sub> ≤1kΩ
I <sub>EBO</sub>	-	-	-10	nA	V <sub>EB</sub> =-6V
*V <sub>CE(sat)1</sub>	-	-39	-60	mV	I <sub>C</sub> =-100mA, I <sub>B</sub> =-5mA
*V <sub>CE(sat)2</sub>	-	-52	-80	mV	I <sub>C</sub> =-500mA, I <sub>B</sub> =-50mA
*V <sub>CE(sat)3</sub>	-	-84	-120	mV	I <sub>C</sub> =-1A, I <sub>B</sub> =-100mA
*V <sub>CE(sat)4</sub>	-	-236	-360	mV	I <sub>C</sub> =-3A, I <sub>B</sub> =-300mA
*R <sub>CE(sat)</sub>	-	79	120	mΩ	I <sub>C</sub> =-3A, I <sub>B</sub> =-300mA
*V <sub>BE(sat)</sub>	-	-965	-1040	mV	I <sub>C</sub> =-3A, I <sub>B</sub> =-300mA
*V <sub>BE(on)</sub>	-	-853	-930	mV	V <sub>CE</sub> =-5V, I <sub>C</sub> =-3A
h <sub>FE1</sub>	100	225	-	-	V <sub>CE</sub> =-5V, I <sub>C</sub> =-10mA
h <sub>FE2</sub>	100	200	300	-	V <sub>CE</sub> =-5V, I <sub>C</sub> =-1A
*h <sub>FE3</sub>	35	-	-	-	V <sub>CE</sub> =-5V, I <sub>C</sub> =-3A
*h <sub>FE4</sub>	-	5	-	-	V <sub>CE</sub> =-5V, I <sub>C</sub> =-10A
f <sub>T</sub>	-	120	-	MHz	V <sub>CE</sub> =-10V, I <sub>C</sub> =-100mA, f=50MHz

Cob	-	31	-	pF	$V_{CB}=-10V, f=1MHz$
ton		42		ns	$I_C=-1A, I_{B1}=-100mA, I_{B2}=100mA,$
toff		636		ns	$V_{CC}=-50V$

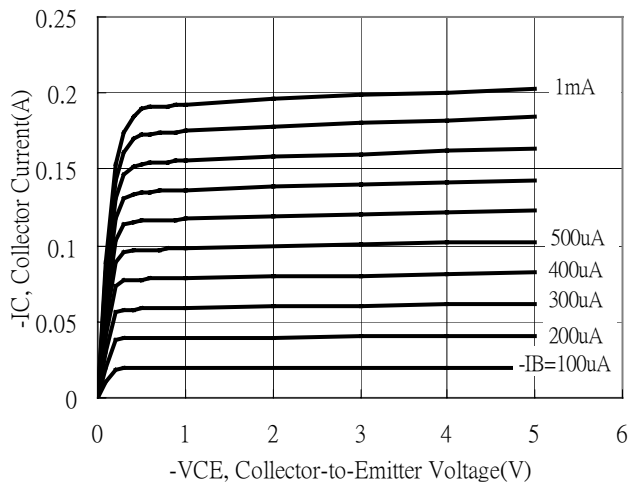
\*Pulse Test: Pulse Width  $\leq 380\mu s$ , Duty Cycle  $\leq 2\%$

**Recommended soldering footprint**

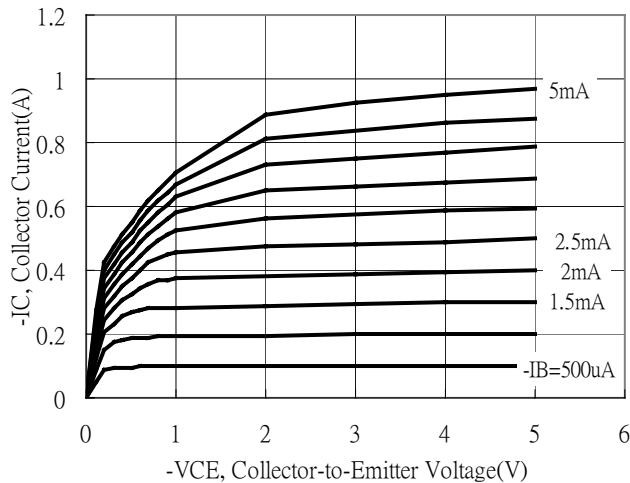


**Typical Characteristics**

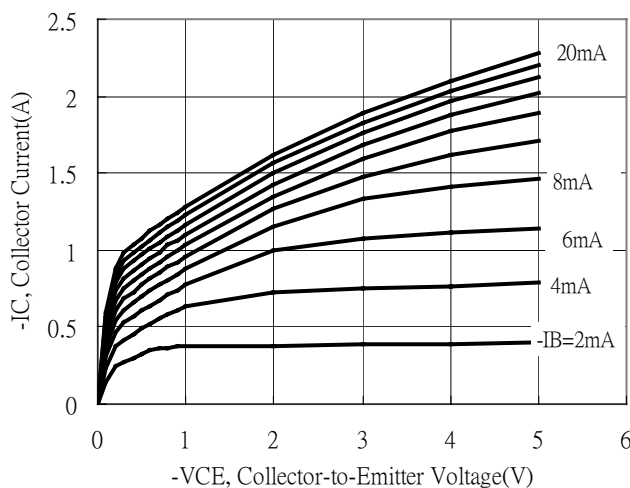
Emitter Grounded Output Characteristics



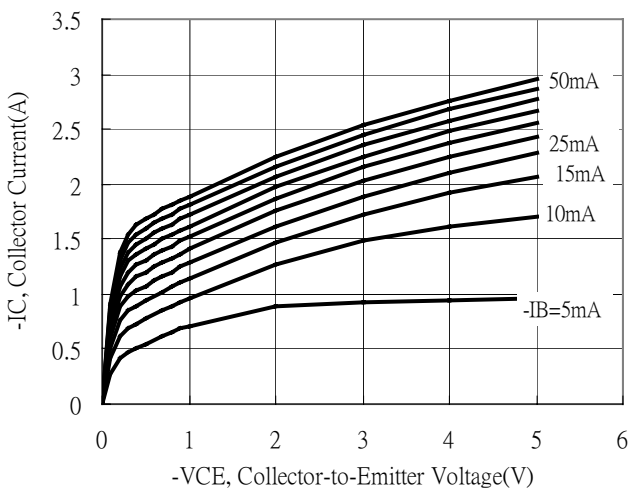
Emitter Grounded Output Characteristics



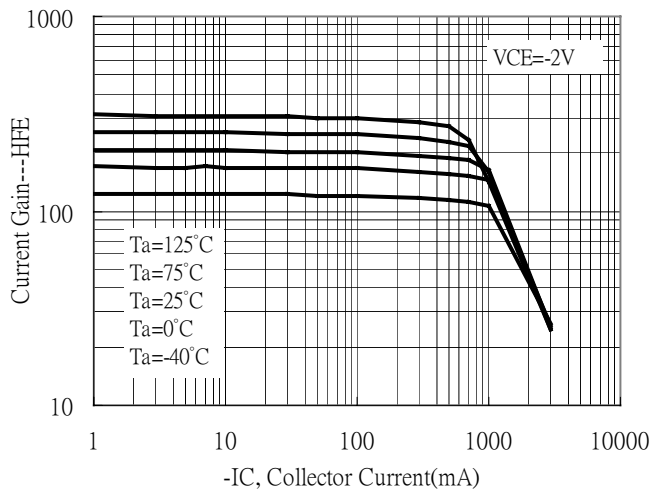
Emitter Grounded Output Characteristics



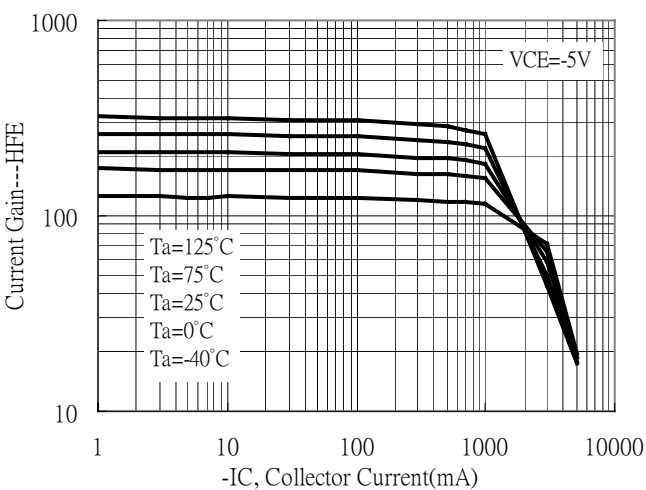
Emitter Grounded Output Characteristics



Current Gain vs Collector Current



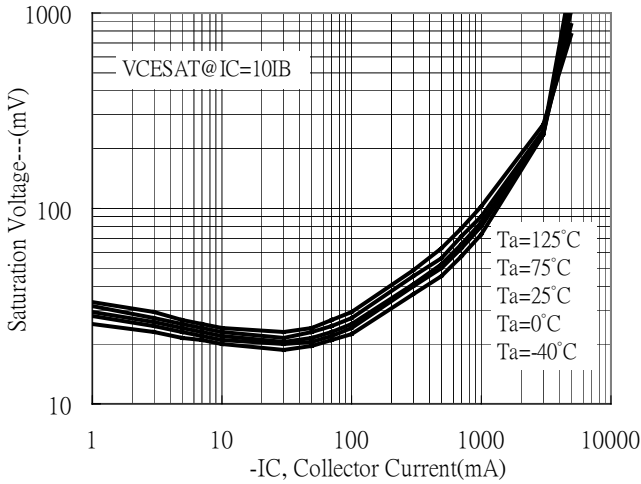
Current Gain vs Collector Current



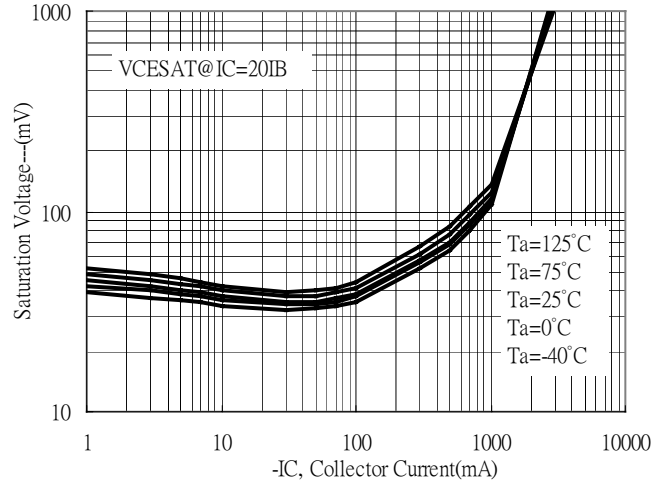


### Typical Characteristics(Cont.)

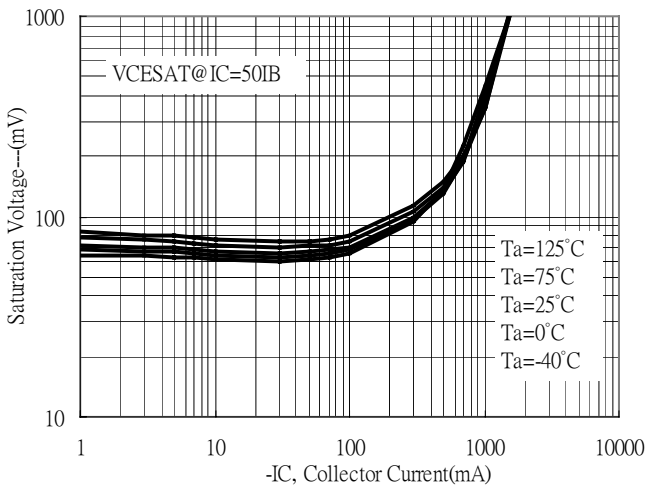
Saturation Voltage vs Collector Current



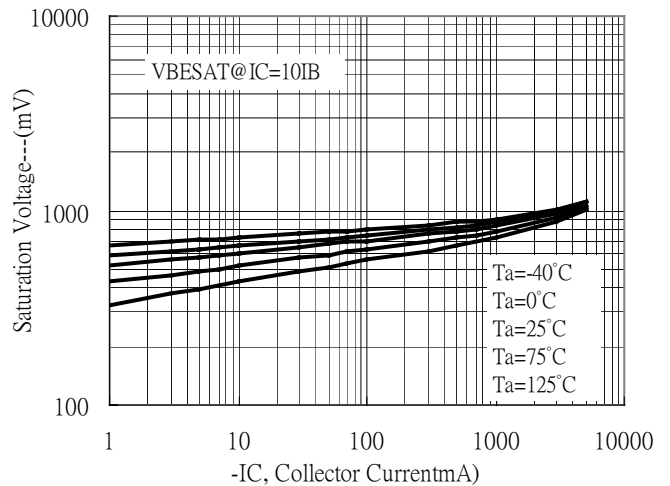
Saturation Voltage vs Collector Current



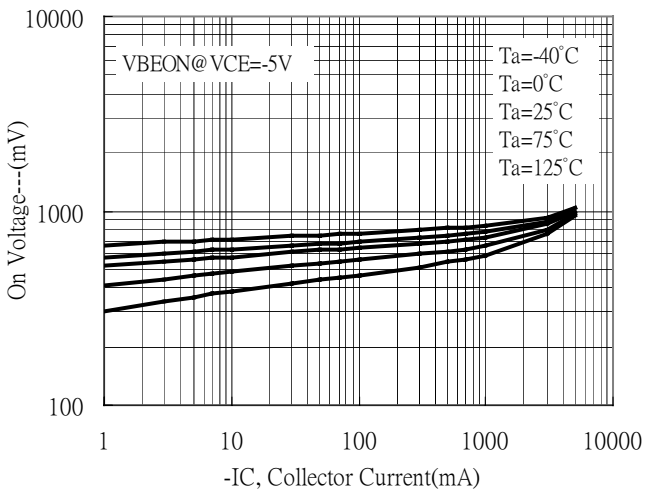
Saturation Voltage vs Collector Current



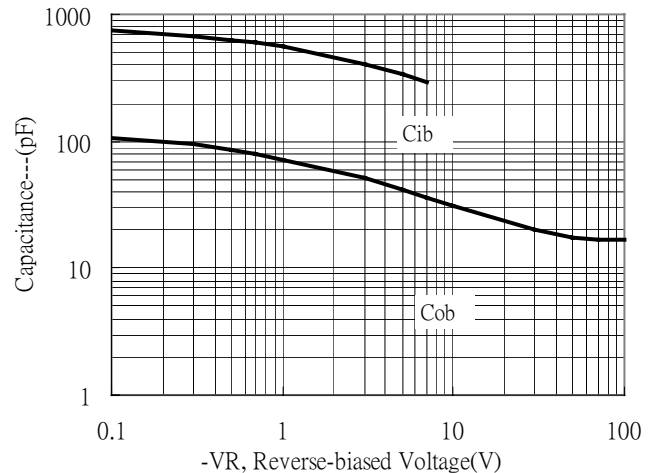
Saturation Voltage vs Collector Current



On Voltage vs Collector Current



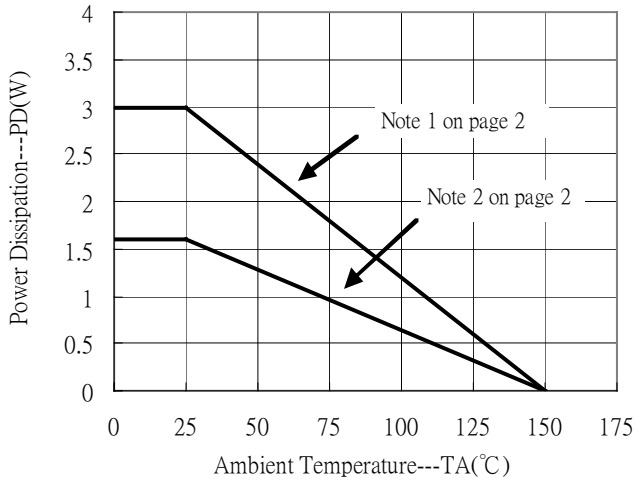
Capacitance vs Reverse-biased Voltage



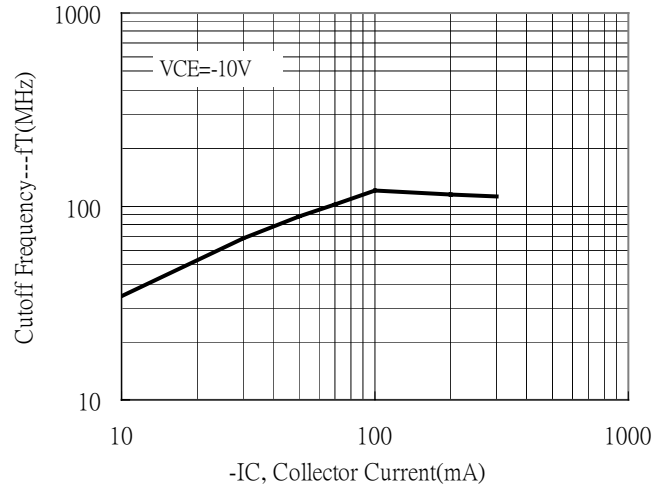


### Typical Characteristics(Cont.)

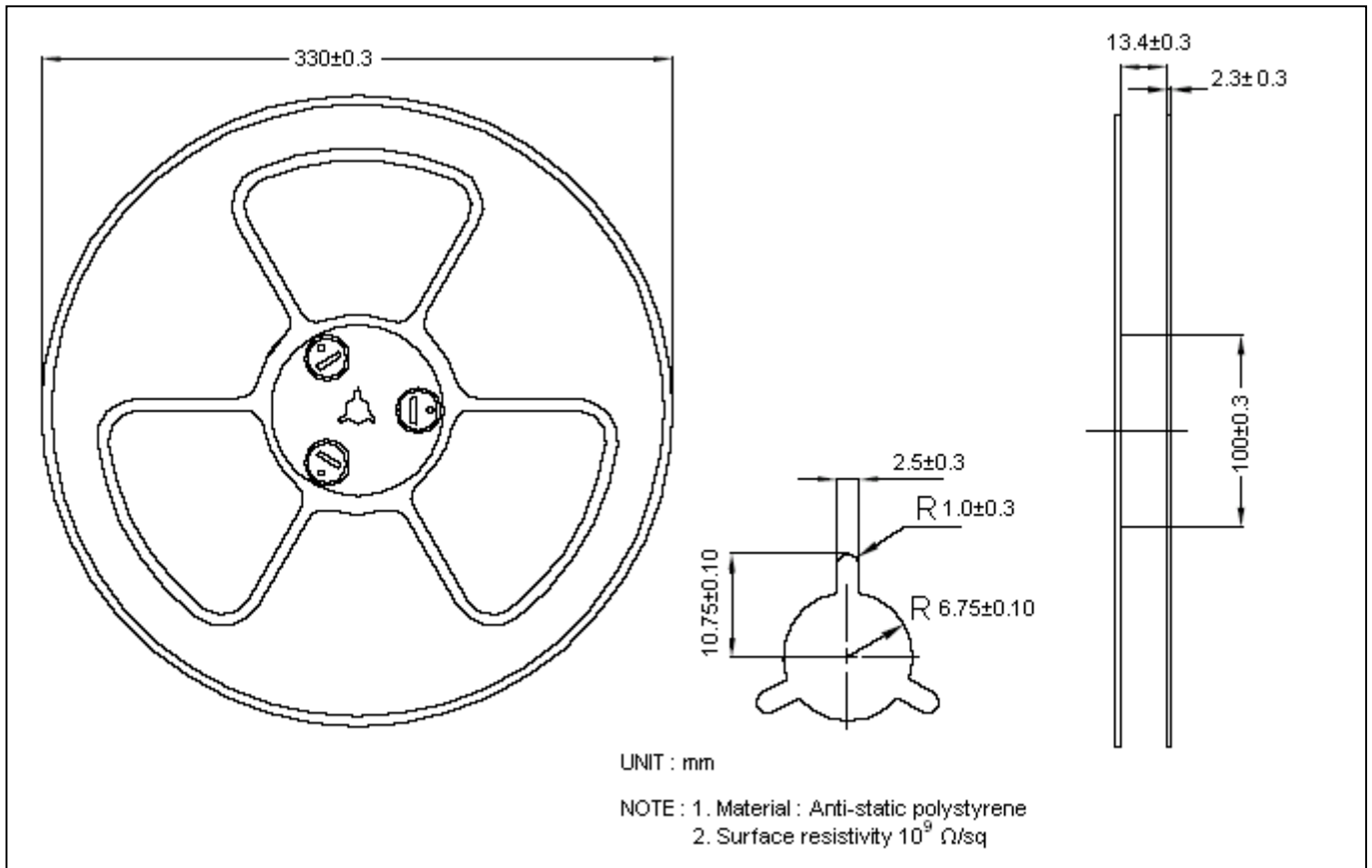
Power Derating Curve



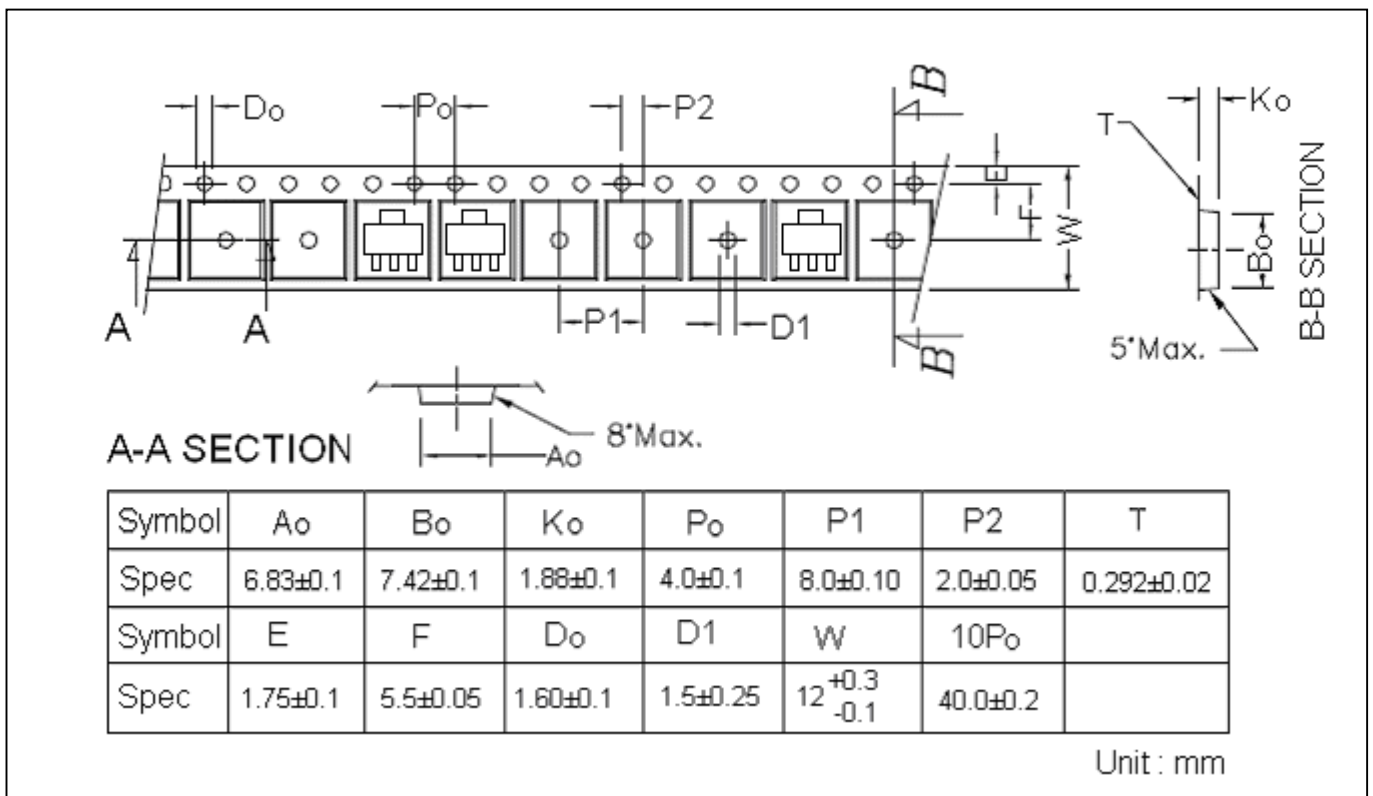
Cutoff Frequency vs Collector Current



**Reel Dimension**



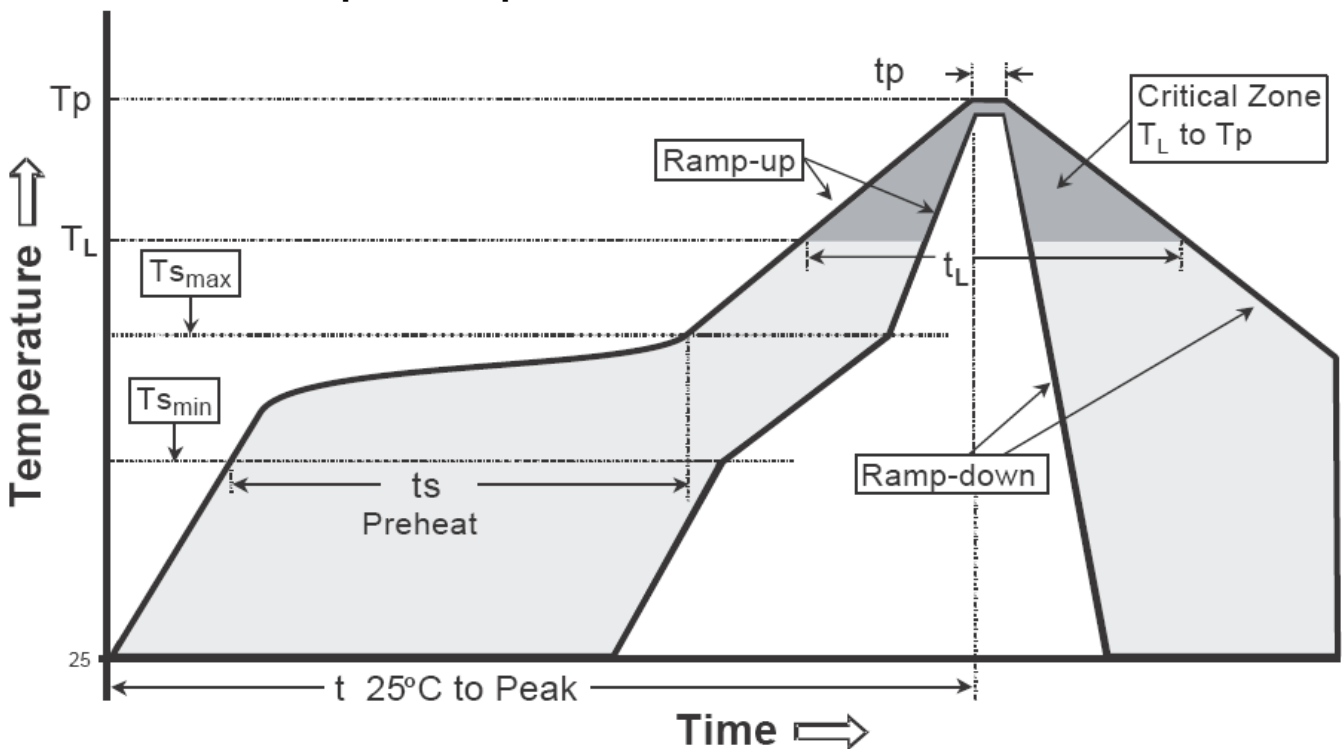
**Carrier Tape Dimension**



**Recommended wave soldering condition**

Product	Peak Temperature	Soldering Time
Pb-free devices	260 +0/-5 °C	5 +1/-1 seconds

**Recommended temperature profile for IR reflow**

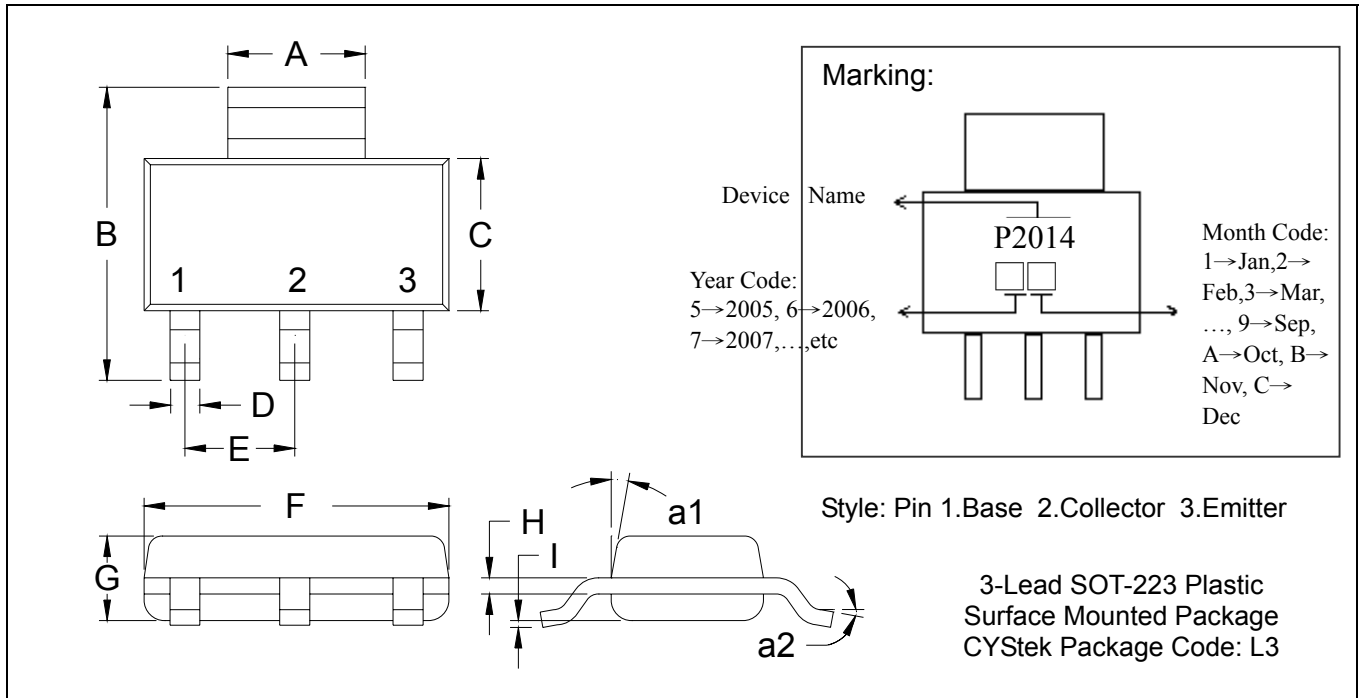


Profile feature	Sn-Pb eutectic Assembly	Pb-free Assembly
Average ramp-up rate (Tsmax to Tp)	3°C/second max.	3°C/second max.
Preheat		
-Temperature Min(Ts min)	100°C	150°C
-Temperature Max(Ts max)	150°C	200°C
-Time(ts min to ts max)	60-120 seconds	60-180 seconds
Time maintained above:		
-Temperature (TL)	183°C	217°C
- Time (tL)	60-150 seconds	60-150 seconds
Peak Temperature(TP)	240 +0/-5 °C	260 +0/-5 °C
Time within 5°C of actual peak temperature(tp)	10-30 seconds	20-40 seconds
Ramp down rate	6°C/second max.	6°C/second max.
Time 25 °C to peak temperature	6 minutes max.	8 minutes max.

Note : All temperatures refer to topside of the package, measured on the package body surface.



**SOT-223 Dimension**



\*: Typical

DIM	Inches		Millimeters		DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	0.1142	0.1220	2.90	3.10	G	0.0551	0.0709	1.40	1.80
B	0.2638	0.2874	6.70	7.30	H	0.0098	0.0138	0.25	0.35
C	0.1299	0.1457	3.30	3.70	I	0.0008	0.0039	0.02	0.10
D	0.0236	0.0315	0.60	0.80	a1	*13°	-	*13°	-
E	*0.0906	-	*2.30	-	a2	0°	10°	0°	10°
F	0.2480	0.2638	6.30	6.70					

- Notes:**
- Controlling dimension: millimeters.
  - Maximum lead thickness includes lead finish thickness, and minimum lead thickness is the minimum thickness of base material.
  - If there is any question with packing specification or packing method, please contact your local CYStek sales office.

**Material:**

- Lead: Pure tin plated
- Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0

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